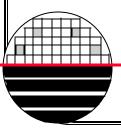
ROCHESTER INSTITUTE OF TECHNOLOGY MICROELECTRONIC ENGINEERING

Anemometer Laboratory

Dr. Lynn Fuller

webpage: http://people.rit.edu/lffeee Microelectronic Engineering Rochester Institute of Technology 82 Lomb Memorial Drive Rochester, NY 14623-5604 Tel (585) 475-2035 Fax (585) 475-5041 Email: Lynn.Fuller@rit.edu Department webpage: http://www.microe.rit.edu



Rochester Institute of Technology

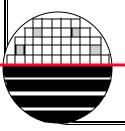
Microelectronic Engineering

4-23-2008 anemometer_lab.ppt

© April 23, 2008 Dr. Lynn Fuller, Professor

OUTLINE

Objective Theory Experimental Set Up Measurements Results Discussion References

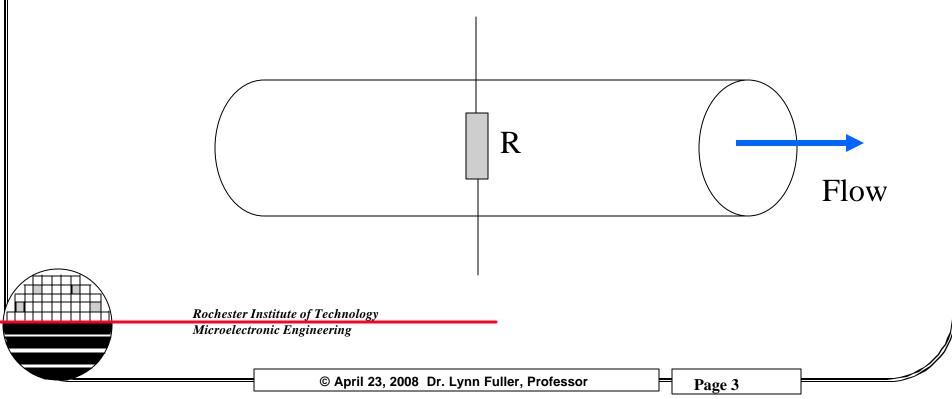


Rochester Institute of Technology

Microelectronic Engineering

OBJECTIVE

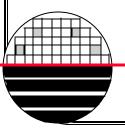
The objective of this laboratory experiment is to build a Thermoanemometer flow sensor, show that it works, and take measurements to experimentally determine; transfer function, calibration, span, resolution and frequency response.



THEORY

A resistor is heated and placed in fluid flow. Flow causes the temperature of the resistor to change and the temperature change causes a change in mobility that causes a change in the value of the resistance. The change in resistance is related to the value of the air flow, the specific heat of the fluid and the physical parameters of the resistor and the air flow chamber.

> Units of flow: sccm = standard cubic cm per min. Slm = standard liter per min.



Rochester Institute of Technology

Microelectronic Engineering

THEORY:

There are many biomedical applications in which it is necessary to measure the flow rate of a fluid, including artificial respirators and drug delivery systems. A common method of measuring the flow rate of a fluid is hot-wire anemometry. When electrical current passes through a resistive element, power is dissipated in that element as heat. This method works on the principle that as a fluid moves over and around that element, the heat will be removed through convection. As long as the fluid temperature and the temperature of the resistive element remain constant, the electrical power dissipated will be equal to the amount of heat removed, as shown in (1).

$$\frac{V^2}{R_s} = \delta(T_s - T_f) \tag{1}$$

Where *V* is the voltage across the sensing element, R_s is the resistance of the sensing element, δ is the heat dissipation constant of the resistive element, T_s is the temperature of the resistive sensing element, and T_f is the fluid temperature. The resistance of the resistive sensing element itself depends on its temperature, but in this application we will use feedback to maintain the element at constant resistance (and temperature). The heat transfer coefficient (δ) can be calculated according to King's law:

$$\delta = a + bv_f^n \qquad (2)$$

Where *a*, *b*, and *n* are calibration coefficients. The values of *a*, *b* and *n* may be found by a three point calibration at three different known flow rates (v_f). Combining (1) and (2) yields:

$$a + bv_f^n = \frac{V^2}{R_s(T_s - T_f)} = \frac{Power}{(T_s - T_f)}$$
 (3)

Rochester Institute of Technology

Microelectronic Engineering

Solving for v_f yields:

$$v_{f} = \left(\frac{\left(\frac{Power}{(T_{s} - T_{f})}\right) - a}{b}\right)^{\frac{1}{n}}$$
(4)

This means that for a given resistive element, the fluid velocity (v_j) is a function of the sensor temperature (T_s) , fluid temperature (T_f) , and power dissipated in the resistive element *(Power)*. If the sensor temperature, fluid temperature, and power dissipated are known, the fluid velocity can be determined.

Rochester Institute of Technology

Microelectronic Engineering

© April 23, 2008 Dr. Lynn Fuller, Professor

THEORY QUESTIONS

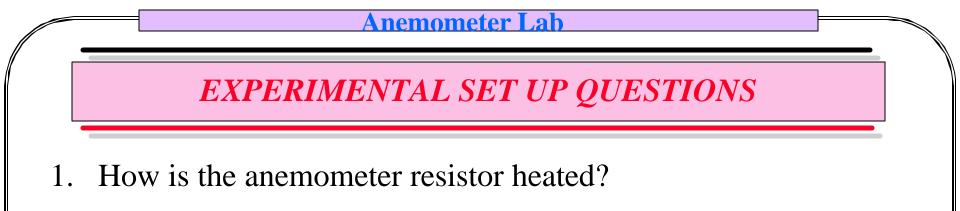
1. What is the theoretical relationship between resistance and temperature? (derive an equation for some stated assumptions) (hint:mobility)

MICROELECTRONIC ENGINEERING		3/13/2005		
CALCULATION OF MOBILITY		Dr. Lynn Fuller		
To use this spreadsheed change the values in protected and should not be changed unless y calculated results are shown in the purple box	ou are sure			
CONSTANTS	VARIABLES		CHOICES	
Tn = T/300 : 1.30	Temp= N total	390 °K 1.00E+18 cm-3	1=ves, 0=no n-type 1 p-type 0 <100>	
Kamins, Muller and Chan; 3rd Ed., 2003, pg 33		mobility	= <u>141</u> cm2/(V-sec)	

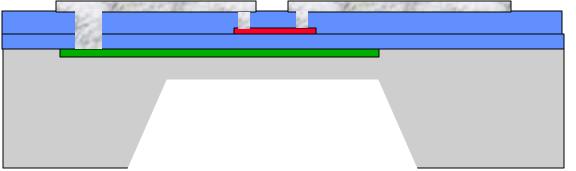
2. What is the theoretical relationship between flow and temperature?

Rochester Institute of Technology

Microelectronic Engineering



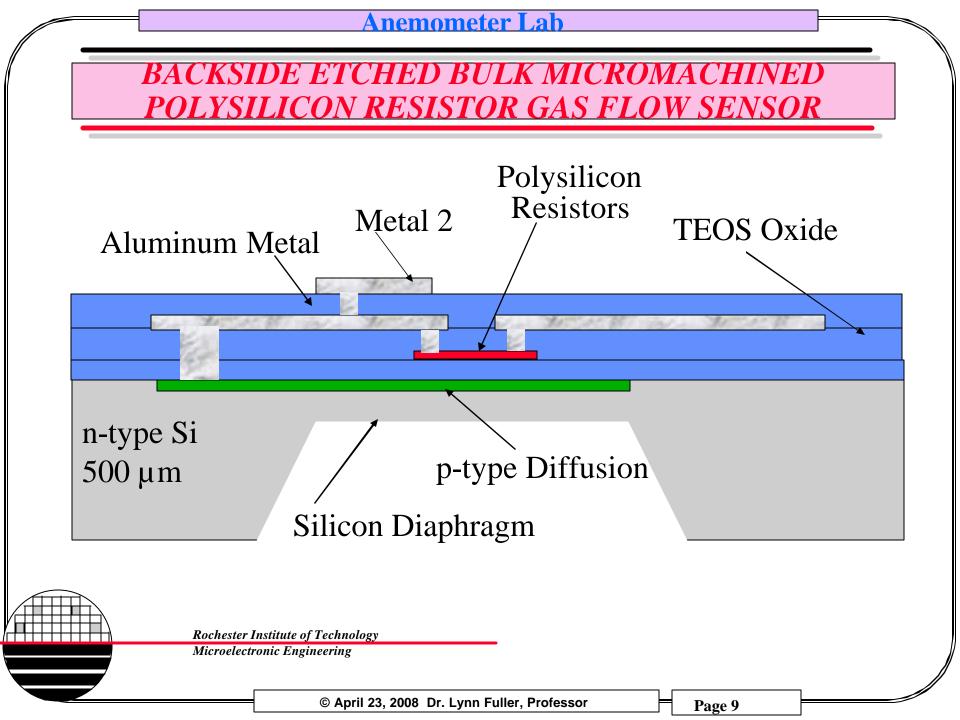
2. What physical properties of the resistor design are important for a good sensor?



3. We expect the resistance to only change by a small amount. Lets come up with a simple but sensitive measurement technique.

Rochester Institute of Technology

Microelectronic Engineering



EXPERIMENTAL SETUP

- 1. How can we control the flow?
- 2. How can we calibrate the flow?

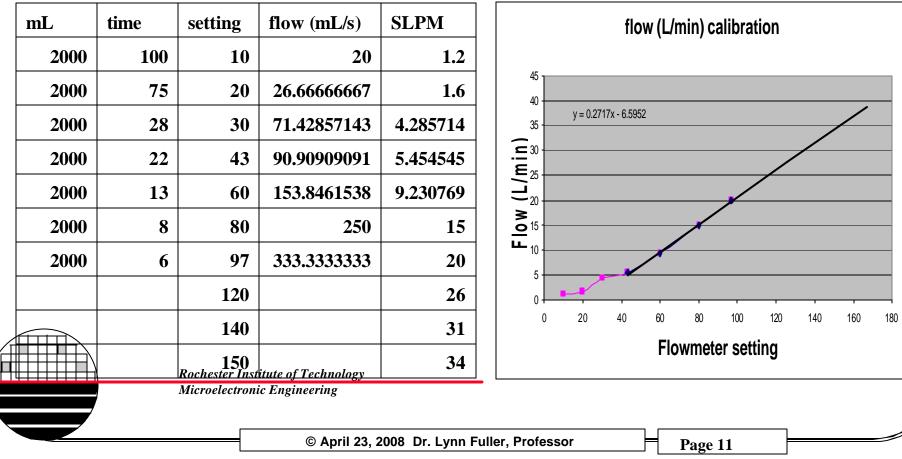


Rochester Institute of Technology Microelectronic Engineering

© April 23, 2008 Dr. Lynn Fuller, Professor

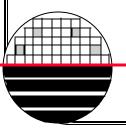
Rotometer

§ Dr. Pearson calibrated the airflow gauge on the bench by finding the amount of time it took to displace 2L of water in an upside down beaker. Manufacturers data sheet for Sapphire Ball gives 28.6 SLM full scale (marked as 150 on the gauge)



MEASUREMENTS

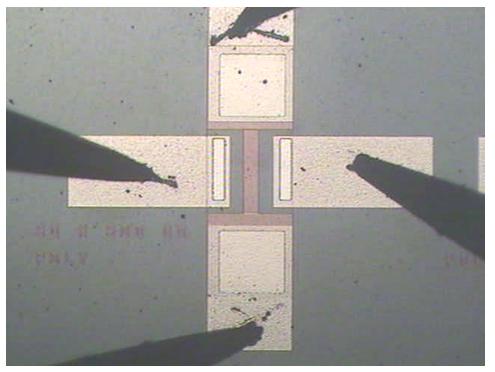
Transfer Function (Output voltage vs flow in sccm) Calibration Span Resolution Frequency Response



Rochester Institute of Technology

Microelectronic Engineering

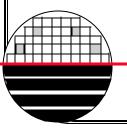
MEMS RESISTOR AND HEATER OVER DIAPHRAGM



Polysilicon Resistor on oxide over a p-type diffused resistor in n-type substrate.

Poly sheet Rho ~ 400hm/sq L=500µm, W=90µm

Diffusion sheet Rho~110ohm/sq L=W=400µm



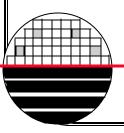
Rochester Institute of Technology

Microelectronic Engineering

© April 23, 2008 Dr. Lynn Fuller, Professor

BASIC MEASUREMENTS

- 1. Calculate Rpoly, Measure Rpoly
- 2. Calculate Rdiff, Measure Rdiff
- 3. Calculate mobility at room T and 100°C for doping 1E19
- 4. Calculate power in heater if 10 volts applied
- 5. Calculate temperature of heater with 10 volts applied
- 6. Measure change in poly resistor when heated by heater
- 7. Measure time response for poly resistor sensor / heater on/off

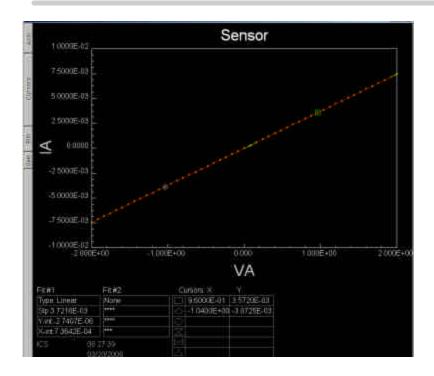


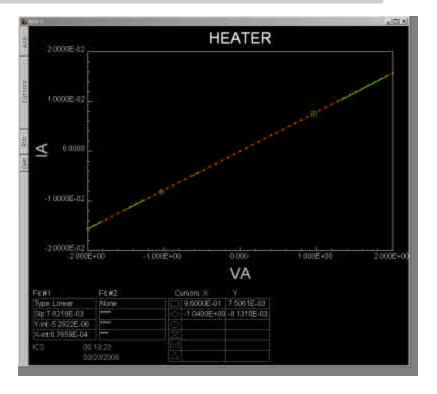
Rochester Institute of Technology

Microelectronic Engineering

© April 23, 2008 Dr. Lynn Fuller, Professor

MEASURED HEATER AND RESISTOR VALUES



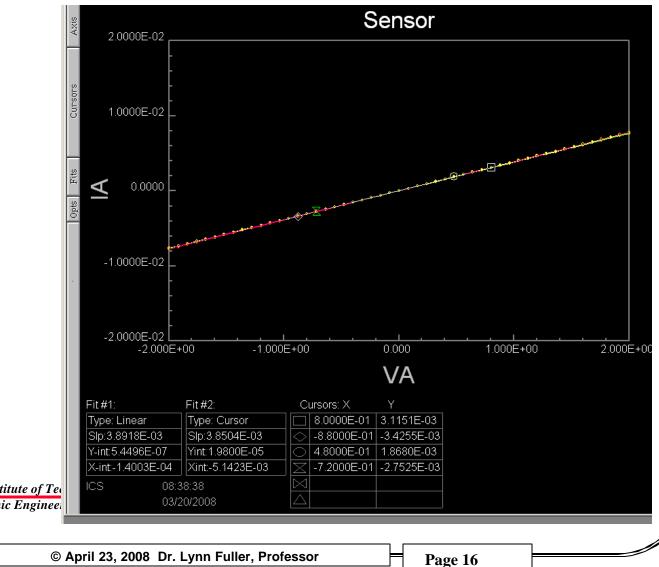


Rochester Institute of Technology

Microelectronic Engineering

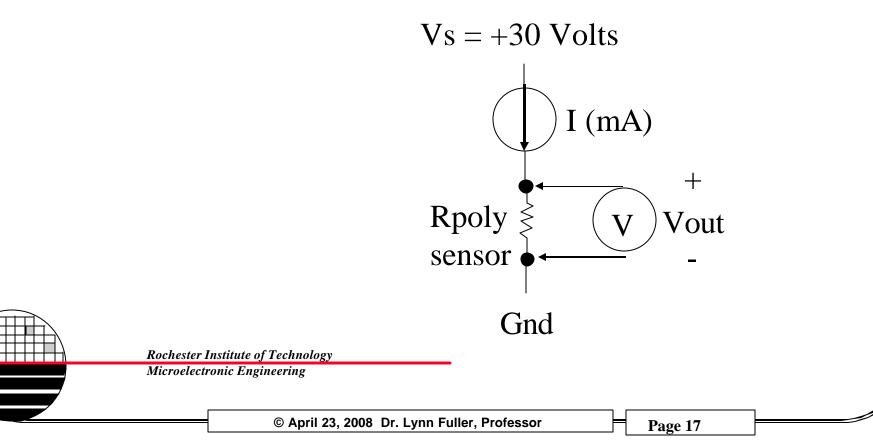
© April 23, 2008 Dr. Lynn Fuller, Professor

HEATING WITH SOLDER IRON

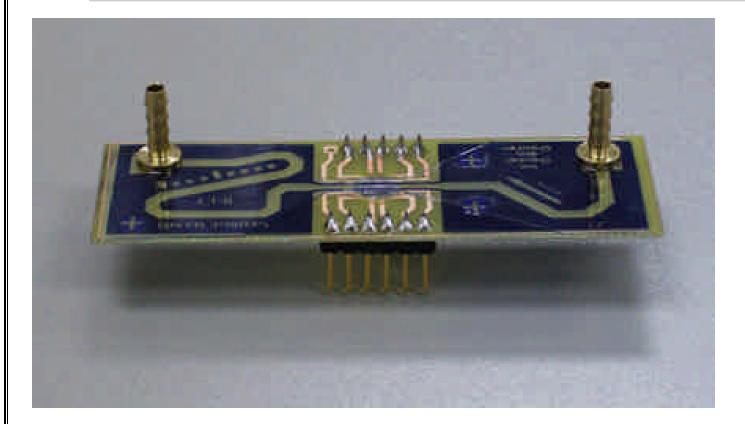


Rochester Institute of Teo Microelectronic Enginee **ANEMOMETER MEASUREMENTS**

Calculate the current needed to generate ~1 watt in the poly resistor. The poly resistor is self heating and will reach some temperature with no gas flow. The resistance will change if gas flows over the resistor. To measure the response use the simple circuit shown.



PACKAGE GAS FLOW SENSOR

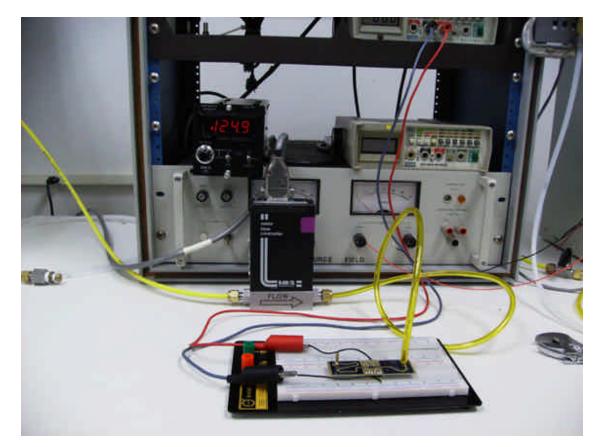


Rochester Institute of Technology

Microelectronic Engineering

© April 23, 2008 Dr. Lynn Fuller, Professor

TEST SET UP FOR GAS FLOW SENSOR

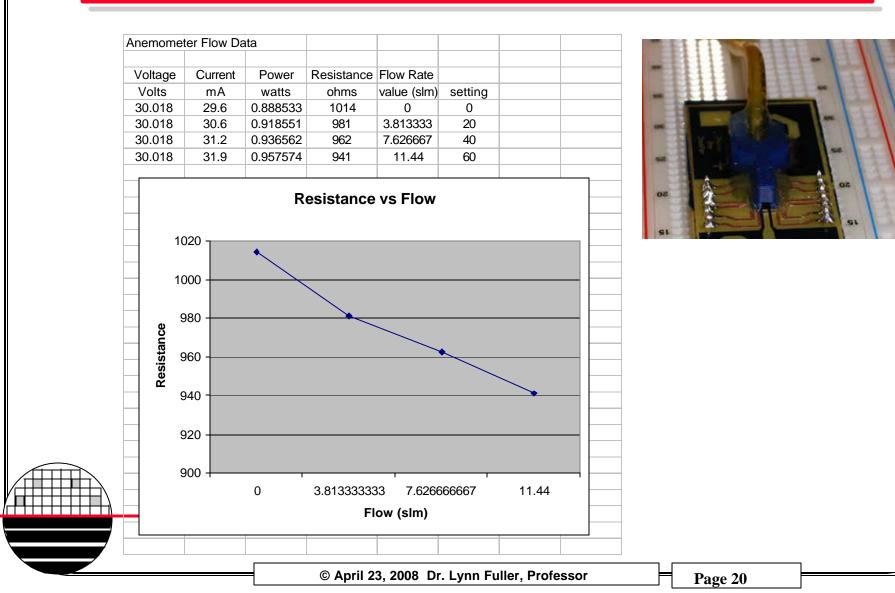


Rochester Institute of Technology

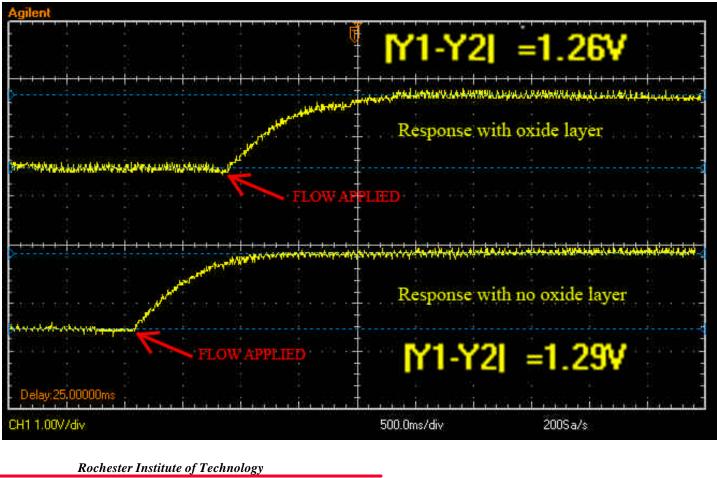
Microelectronic Engineering

© April 23, 2008 Dr. Lynn Fuller, Professor

RESULTS FROM PACKAGED SENSOR



STEP RESPONSE



Microelectronic Engineering

	A	nem	ome	eter]	Lab
--	---	-----	-----	--------	-----

RESULTS

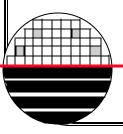
It works!

Calibration was achieved by.....

A plot of output versus flow is shown. An equation for this relationship (transfer function) has been obtained and is given below.

We were able to measure air flows from 0 to xxxx (span) with a resolution of yyyy.

The frequency response was determined by zzzz and is given below in graphical and analytical form.



Rochester Institute of Technology

Microelectronic Engineering

DISCUSSION

A simple yet effective anemometer was built, calibrated and evaluated. The device performance was investigated and shown to have Improvements could be made by

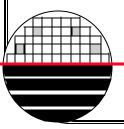
Rochester Institute of Technology

Microelectronic Engineering

© April 23, 2008 Dr. Lynn Fuller, Professor

REFERENCES

1. Handbook of Modern Sensors, Jacob Faraden, Springer



Rochester Institute of Technology

Microelectronic Engineering

© April 23, 2008 Dr. Lynn Fuller, Professor

INSTRUCTORS CHECK LIST

Show MEMS chip Take a Picture Measure Heater Resistance using HP4145 Measure Sensor Resistance using HP4145 Measure Sensor Resistance with and without light Measure Sensor Resistance with voltmeter and current meter Measure Sensor I and V at 50 mV applied (no self heating) Measure Sensor I and V at 30 V applied (self heating ~1watt) Measure Packaged sensor no flow Measure Packaged sensor with flow, take data at different flows Measure response to step change in flow Build electronic constant resistance circuit

Rochester Institute of Technology

Microelectronic Engineering